

# CD54HC125, CD74HC125, CD54HCT125

Data sheet acquired from Harris Semiconductor SCHS143C

November 1997 - Revised August 2003

High-Speed CMOS Logic Quad Buffer, Three-State

#### Features

- Three-State Outputs
- Separate Output Enable Inputs
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity:  $N_{IL}$  = 30%,  $N_{IH}$  = 30% of  $V_{CC}$  at  $V_{CC}$  = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility, V<sub>IL</sub>= 0.8V (Max), V<sub>IH</sub> = 2V (Min)
  - CMOS Input Compatibility, I  $_I \leq 1 \mu A$  at  $V_{OL},\,V_{OH}$

## Description

The 'HC125 and 'HCT125 contain 4 independent three-state buffers, each having its own output enable input, which when "HIGH" puts the output in the high impedance state.

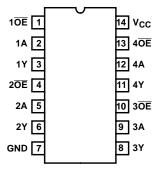
#### **Ordering Information**

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC125F3A	-55 to 125	14 Ld CERDIP
CD54HCT125F3A	-55 to 125	14 Ld CERDIP
CD74HC125E	-55 to 125	14 Ld PDIP
CD74HC125M	-55 to 125	14 Ld SOIC
CD74HC125MT	-55 to 125	14 Ld SOIC
CD74HC125M96	-55 to 125	14 Ld SOIC
CD74HCT125E	-55 to 125	14 Ld PDIP
CD74HCT125M	-55 to 125	14 Ld SOIC
CD74HCT125MT	-55 to 125	14 Ld SOIC
CD74HCT125M96	-55 to 125	14 Ld SOIC

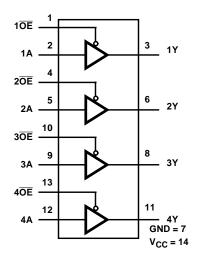
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250

#### **Pinout**

CD54HC125, CD54HCT125 (CERDIP) CD74HC125, CD74HCT125 (PDIP, SOIC) TOP VIEW



# Functional Diagram



**TRUTH TABLE** 

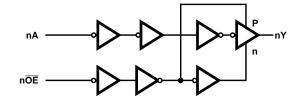
INP	OUTPUTS			
nA	nOE	nY		
Н	L	Н		
L	L	L		
Х	Н	Z		

H= High Voltage Level

L= Low Voltage Level X= Don't Care

Z= High Impedance, OFF State

# Logic Diagram



#### CD54HC125, CD74HC125, CD54HCT125, CD74HCT125

## **Absolute Maximum Ratings**

#### 

#### **Thermal Information**

Thermal Resistance (Typical, Note 1)	$\theta_{JA}$ (°C/W)
E (PDIP) Package	. 80
M (SOIC) Package	. 86
Maximum Junction Temperature	150 <sup>o</sup> C
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

#### **Operating Conditions**

Temperature Range (T <sub>A</sub> )55°C to 125°C Supply Voltage Range, V <sub>CC</sub>
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> 0V to V <sub>CC</sub>
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

#### **DC Electrical Specifications**

			TEST CONDITIONS			25°C			O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	V <sub>IH</sub>	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V <sub>IL</sub>	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V <sub>OH</sub>	V <sub>IH</sub> or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads		V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	1		-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Voltage TTL Loads			-7.8	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V <sub>OL</sub>	V <sub>IH</sub> or	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads		$V_{IL}$	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			6	4.5	-	-	0.26	-	0.33	-	0.4	V
Voltage TTL Loads			7.8	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	l <sub>Ι</sub>	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μА

## CD54HC125, CD74HC125, CD54HCT125, CD74HCT125

## DC Electrical Specifications (Continued)

			ST ITIONS			25°C		-40°C T	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μА
Three-State Leakage Current	l <sub>OZ</sub>	V <sub>IL</sub> or V <sub>IH</sub>	-	6	-	-	±0.5	-	±5	-	±10	μА
HCT TYPES	•						•					•
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	II	V <sub>CC</sub> to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI <sub>CC</sub> (Note 2)	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА
Three-State Leakage Current	loz	V <sub>IL</sub> or V <sub>IH</sub>	-	5.5	-	-	±0.5	-	±5	-	±10	μΑ

#### NOTE:

2. For dual-supply systems theoretical worst case ( $V_I$  = 2.4V,  $V_{CC}$  = 5.5V) specification is 1.8mA.

## **HCT Input Loading Table**

INPUT	UNIT LOADS
nA, n <del>OE</del>	1

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications table, e.g., 360 $\mu$ A max at 25 $^{o}$ C.

## CD54HC125, CD74HC125, CD54HCT125, CD74HCT125

## **Switching Specifications** Input $t_r$ , $t_f = 6ns$

		TEST		25	o <sub>C</sub>	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	TYP	MAX	MAX	MAX	UNIT
HC TYPES								
Propagation Delay Time nA to nY	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	ı	100	125	150	ns
TIA TO TT			4.5	-	20	25	30	ns
		C <sub>L</sub> = 15pF	5	8	-	-	-	ns
		CL = 50pF	6	-	17	21	26	ns
Enable Delay Time	t <sub>PZL</sub> , t <sub>PZH</sub>	C <sub>L</sub> = 50pF	2	-	125	155	190	ns
			4.5	-	25	31	38	ns
		C <sub>L</sub> = 15pF	5	10	-	-	-	ns
		CL = 50pF	6	-	21	26	32	ns
Disable Delay Time	t <sub>PLZ</sub> , t <sub>PHZ</sub>	CL = 50pF	2	-	125	155	190	ns
		C <sub>L</sub> = 50pF	4.5	-	25	31	38	ns
		C <sub>L</sub> = 15pF	5	10	-	-	-	ns
		CL = 50pF	6	-	21	26	32	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	60	75	90	ns
			4.5	-	12	15	18	ns
			6	-	10	13	15	ns
Input Capacitance	C <sub>I</sub>	-	-	-	10	10	10	pF
Three-State Output Capacitance	CO	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	-	5	29	-	-	-	pF
HCT TYPES			!				<u> </u>	
Propagation Delay Time	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	25	31	38	ns
nA to nY		C <sub>L</sub> = 15pF	5	10	-	-	-	ns
Output Enable Time	t <sub>PZL</sub> , t <sub>PZH</sub>	C <sub>L</sub> = 50pF	4.5	-	25	31	38	ns
		C <sub>L</sub> = 15pF	5	10	-	-	-	ns
Output Disabling Time	t <sub>PLZ</sub> , t <sub>PHZ</sub>	C <sub>L</sub> = 50pF	4.5	-	28	35	42	ns
		C <sub>L</sub> = 15pF	5	11	-	-	-	ns
Output Transition Times	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	12	15	18	ns
Input Capacitance	C <sub>I</sub>	-	-	-	10	10	10	pF
Three-State Output Capacitance	CO	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	-	5	34	-	-	-	pF

- 3. C<sub>PD</sub> is used to determine the dynamic power consumption, per channel.
   4. P<sub>D</sub> = V<sub>CC</sub><sup>2</sup> f<sub>i</sub> (C<sub>PD</sub> + C<sub>L</sub>) where f<sub>i</sub> = Input Frequency, f<sub>O</sub> = Output Frequency, C<sub>L</sub> = Output Load Capacitance, V<sub>CC</sub> = Supply Voltage.

#### Test Circuits and Waveforms

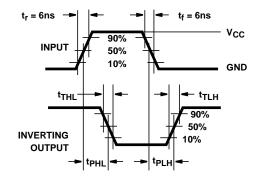


FIGURE 1. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

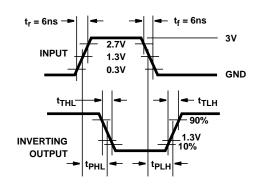


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

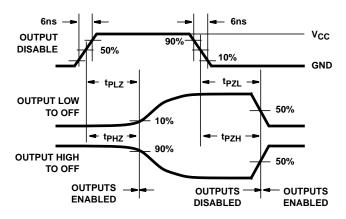


FIGURE 3. HC THREE-STATE PROPAGATION DELAY WAVEFORM

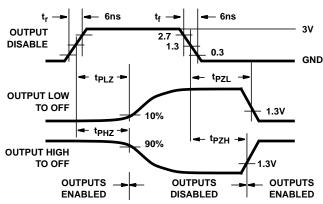
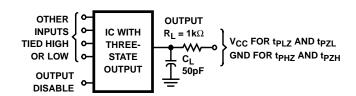


FIGURE 4. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



NOTE: Open drain waveforms  $t_{PLZ}$  and  $t_{PZL}$  are the same as those for three-state shown on the left. The test circuit is Output  $R_L = 1k\Omega$  to  $V_{CC}$ ,  $C_L = 50pF$ .

FIGURE 5. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT





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#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD54HC125F	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HC125F	Samples
CD54HC125F3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8772101CA CD54HC125F3A	Samples
CD54HCT125F3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HCT125F3A	Samples
CD74HC125E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC125E	Samples
CD74HC125EE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC125E	Samples
CD74HC125M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC125M	Samples
CD74HC125M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC125M	Samples
CD74HC125M96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC125M	Samples
CD74HC125ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC125M	Samples
CD74HC125MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC125M	Samples
CD74HC125MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC125M	Samples
CD74HCT125E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT125E	Samples
CD74HCT125M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT125M	Samples
CD74HCT125M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT125M	Samples
CD74HCT125M96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT125M	Samples
CD74HCT125M96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT125M	Samples
CD74HCT125MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT125M	Samples

#### PACKAGE OPTION ADDENDUM



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(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF CD54HC125, CD54HC1125, CD74HC125, CD74HC1125:

Catalog: CD74HC125, CD74HCT125

Automotive: CD74HC125-Q1, CD74HC125-Q1





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• Military: CD54HC125, CD54HCT125

NOTE: Qualified Version Definitions:

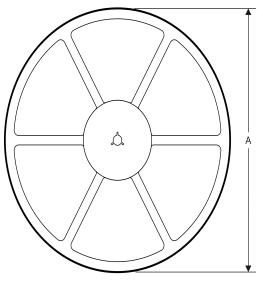
- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications

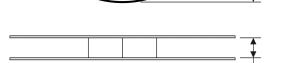
## PACKAGE MATERIALS INFORMATION

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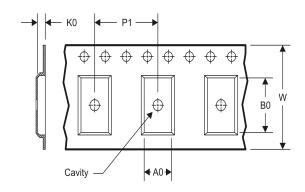
## TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**





#### **TAPE DIMENSIONS**



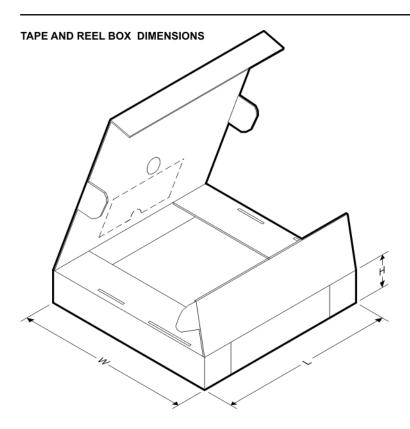
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### TAPE AND REEL INFORMATION

#### \*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC125M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC125MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCT125M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCT125MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

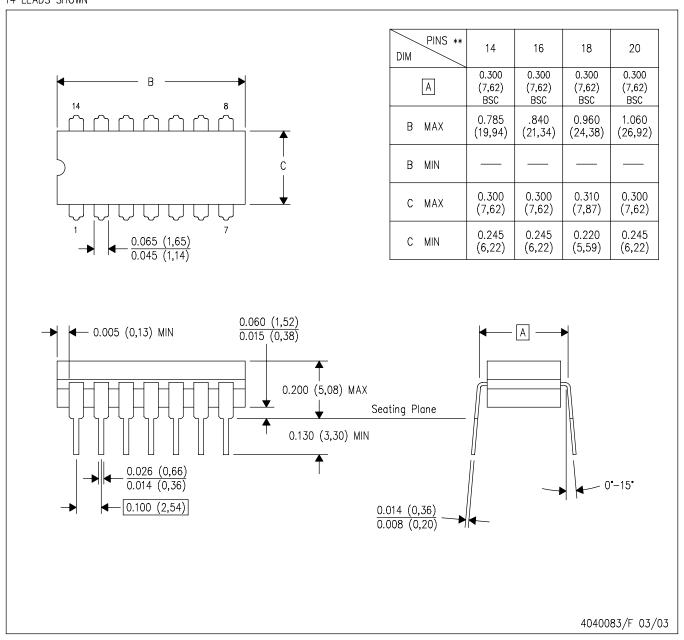
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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC125M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HC125MT	SOIC	D	14	250	367.0	367.0	38.0
CD74HCT125M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HCT125MT	SOIC	D	14	250	367.0	367.0	38.0

#### 14 LEADS SHOWN

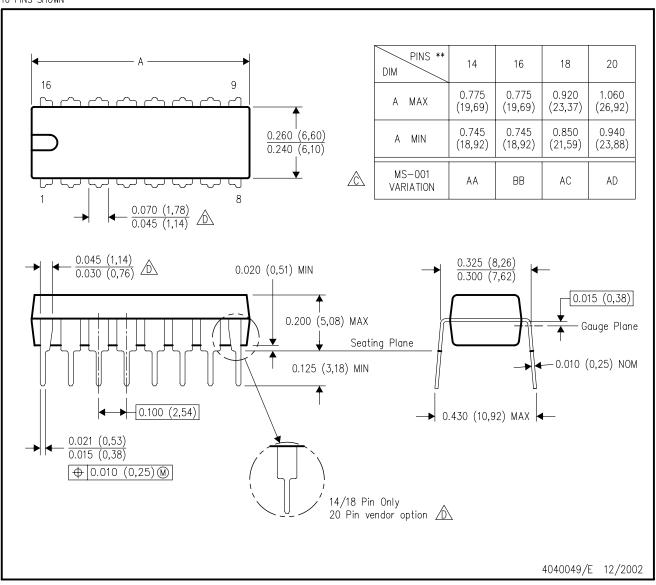


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



## D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



# D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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